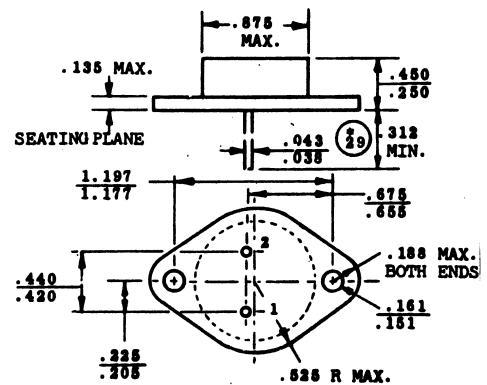


PARAMETERS

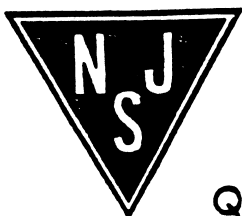
2N4901
 SI PNP POWER BJT

Description: Si PNP Power BJT

Manufacturer.....	
Mil/High-Rel? (Y/N).....	
Ic Max. (A).....	5.0
Vbr CEO.....	40
Vbr CBO.....	40
Max. PD (W).....	87
Derate (Amb) (W/xC).....	500m
Min hFE.....	20
Max. hFE.....	80
@Ic (test) (A).....	1.0
@VCE (V).....	2.0
Trans. Freq (Hz) Min.....	4.0M
Icbo Max. @Vcb Max. (A).....	100uw
R(sat) (j).....	
Tr Max. (s).....	
t(f) Max. (S).....	
Oper. Temp (x C) Max.....	175u
Pkg Style.....	TO-3
Surface Mounted (Y/N).....	N
Pinout Equivalence Number.....	3-14



u Junction Temperature 2 It(rms) w ICEX



Quality Semi-Conductors